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Vishay General Semiconductor

# Dual High Voltage TMBS<sup>®</sup> (Trench MOS Barrier Schottky) Rectifier

Ultra Low  $V_F = 0.43$  V at  $I_F = 5$  A

## FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

## **TYPICAL APPLICATIONS**

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters, and reverse battery protection.

### **MECHANICAL DATA**

Case: TO-220AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

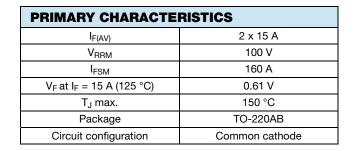
Mounting Torque: 10 in-lbs maximum

<b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	V31103C	UNIT	
Maximum repetitive peak reverse voltage		V <sub>RRM</sub>	100	V	
Maximum average forward rectified current (fig. 1)	per device	1	30	A	
	per diode	IF(AV)	15		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I <sub>FSM</sub>	160	А	
Operating junction temperature range		T <sub>J</sub> <sup>(1)</sup>	-40 to +150	℃	
Storage temperature range		T <sub>STG</sub>	-55 to +150	U	

Note

 $^{(1)}$  The heat generated must be less than the thermal conductivity from junction to ambient: dP\_D/dT\_J <1/  $R_{\theta JA}$ 









ROHS COMPLIANT



# V31103C

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<b>ELECTRICAL CHARACTERISTICS</b> ( $T_J = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	TEST CO	NDITIONS	SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage	I <sub>F</sub> = 5 A	T <sub>J</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.50	-	- V
	I <sub>F</sub> = 7.5 A			0.55	-	
	I <sub>F</sub> = 15 A			0.68	0.73	
	I <sub>F</sub> = 5 A	T <sub>J</sub> = 125 °C		0.43	-	
	I <sub>F</sub> = 7.5 A			0.49	-	
	I <sub>F</sub> = 15 A			0.61	0.66	
Reverse current at rated V <sub>R</sub> per diode	V 70.V	T <sub>J</sub> = 25 °C	I <sub>R</sub> (2)	0.012	-	- mA
	V <sub>R</sub> = 70 V	T <sub>J</sub> = 125 °C		6.5	-	
	V <sub>R</sub> = 100 V	T <sub>J</sub> = 25 °C		-	0.9	
		T <sub>J</sub> = 125 °C		16.0	35	
Typical junction capacitance	4 V, 1MHz	-	CJ	1600	-	pF

#### Notes

 $^{(1)}\,$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

<sup>(2)</sup> Pulse test: Pulse width  $\leq$  5 ms

<b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER	SYMBOL	V31103C	UNIT		
Typical thermal resistance per device	R <sub>0JC</sub> <sup>(1)</sup>	1.0	°C/W		

#### Note

<sup>(1)</sup> Thermal resistance junction-to-case to follow JEDEC<sup>®</sup> 51-14 transient dual interface test method (TDIM)

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
V31103C-M3/P	1.88	Р	50/tube	Tube		



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## **RATINGS AND CHARACTERISTICS CURVES** ( $T_A = 25$ °C unless otherwise noted)

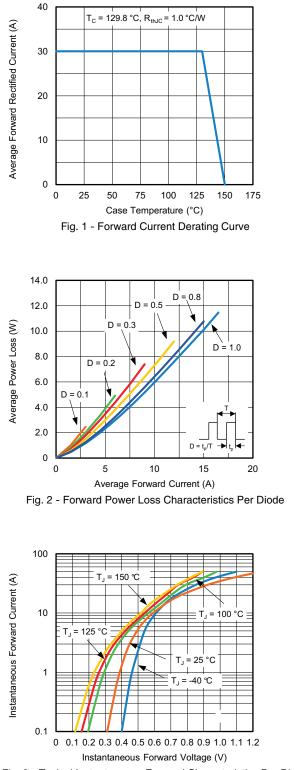
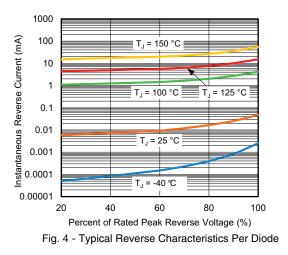
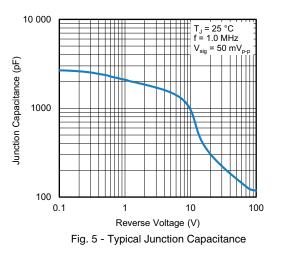
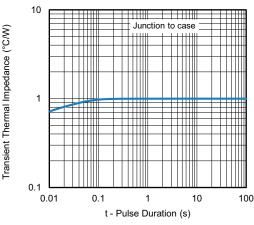
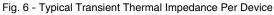


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode









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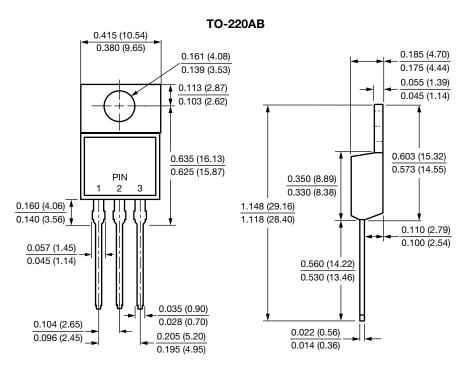
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## **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)





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